

SAMTM Data Sheet SAM-1064-13-500fs-x, λ = 1064 nm

 $\lambda = 1064 \text{ nm}$ Laser wavelength

High reflection band $\lambda = 1020 ... 1100 nm$

Absorbance $A_0 = 13 \%$ $\Delta R = 8 \%$ Modulation depth $A_{ns} = 5 \%$ Non-saturable loss

 $\Phi_{\text{sat}} = 60 \, \mu \text{J/cm}^2$ Saturation fluence

Relaxation time constant $\tau \sim 500 \text{ fs}$

 Φ = 2.5 mJ/cm² Damage threshold

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

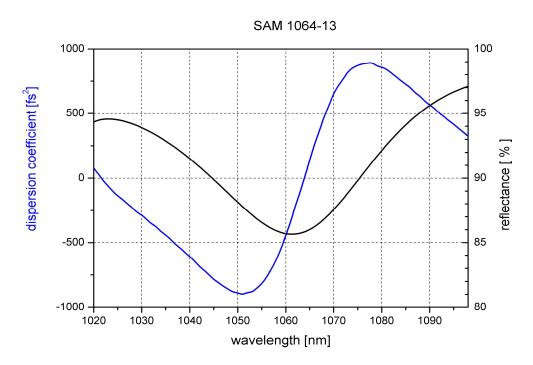
Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

 $\mathbf{x} = 0$ unmounted

x = 12.7 gglued on a gold plated Cu-cylinder with 12.7 mm \varnothing glued on a gold plated Cu-cylinder with 25.4 mm \varnothing x = 25.4 gx = 12.7 ssoldered on a gold plated Cu-cylinder with 12.7 mm \varnothing soldered on a gold plated Cu-cylinder with 25.4 mm Ø x = 25.4 sx = FCmounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance and dispersion coefficient D₂





Dispersion coefficient
$$D_2(\omega)=rac{\partial^2 \varphi}{\partial \omega^2}$$
 with φ - reflected phase
$$\omega=2\pi\,rac{c}{\lambda}\,$$
 - angular frequency